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|  | <h2 style="color: red;">DS1250YP-100+</h2> | |
| | Hersteller-Teilenummer: | DS1250YP-100+ |
|  | Hersteller / Marke: | Maxim Integrated |
| | Teil der Beschreibung: | IC NVSRAM 4M PARALLEL 34PWRCAP |
| Datenblätter: |  DS1250YP-100+.pdf | |
| RoHs Status: | Bleifrei / RoHS-konform | |
| Lagerzustand: | New original, 500 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| <p>Image may be representation. See specs for product details.</p> | | |

Spezifikationen

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|---|---|
| Teilenummer | DS1250YP-100+ |
| Hersteller | Maxim Integrated |
| Beschreibung | IC NVSRAM 4M PARALLEL 34PWRCAP |
| Kategorie | Integrierte Schaltungen (ICs) > Erinnerung |
| Teilstatus | 500 pcs Stock |
| detaillierte Beschreibung | NVSRAM (Non-Volatile SRAM) Memory IC 4Mb (512K |
| Serie | - |
| Technologie | NVSRAM (Non-Volatile SRAM) |
| Betriebstemperatur | 0°C ~ 70°C (TA) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | 34-PowerCap™ Module |
| Supplier Device-Gehäuse | 34-PowerCap Module |
| Spannungsversorgung | 4.5 V ~ 5.5 V |
| Speichertyp | Non-Volatile |
| Speichergröße | 4Mb (512K x 8) |
| Zugriffszeit | 100ns |
| Speicherformat | NVSRAM |
| Schreibzyklus Zeit - Wort, Seite | 100ns |
| Speicherschnittstelle | Parallel |
| Verpackung | Tube |
| Basisteilenummer | DS1250Y |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 2 (1 Year) |

DS1250YP-100+ ist neu im Original, Suche DS1250YP-100+ Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DS1250YP-100+ Maxim Integrated mit Garantie und Vertrauen. Anfrage DS1250YP-100+: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|--|--|
|  <p>DS1250YP-70+ Maxim Integrated IC NVSRAM 4MBIT 70NS 34PCM</p> |  <p>DS1250Y-70IND+ Maxim Integrated IC NVSRAM 4MBIT 70NS 32EDIP</p> |  <p>DS1250YP-100 Maxim Integrated IC NVSRAM 4MBIT 100NS 34PCM</p> |  <p>DS1250YL-70 Maxim Integrated IC NVSRAM 4MBIT 70NS 34LPM</p> |
|  <p>DS1250YL-70-IND Maxim Integrated IC NVSRAM 4MBIT 70NS 34LPM</p> |  <p>DS1250YL-100 Maxim Integrated IC NVSRAM 4MBIT 100NS 34LPM</p> |  <p>DS1250YP-100IND+ DALLAS DS1250YP-100IND+ DALLAS</p> |  <p>DS1250YP-70IND Maxim Integrated IC NVSRAM 4M PARALLEL 34PWRCAP</p> |

heiße Teile

Mehr

- | | | | | |
|--------------------|-----------------|-----------------|-----------------|--------------------|
| DS1233Z-15/TR | DS1233Z-15TR | DS1233Z-5 | DS1233Z-5+T&R | DS1233Z-5TR |
| DS1237-1 | DS1244Y-120 | DS1244Y-150 | DS1245W-100+ | DS1245Y-100 |
| DS1245Y-120IND | DS1245Y-150 | DS1245Y-70+ | DS1250AB-70+ | DS1250W-100+ |
| DS1250W-100IND+ | DS1250W-150IND+ | DS1250Y-070 | DS1250Y-070IND+ | DS1250Y-100+ |
| DS1250Y-120+ | DS1250Y-150 | DS1250Y-70 | DS1250Y-70+ | DS1250Y-70IND |
| DS1250YP-70+ | DS1251AB-120IND | DS1251W-150IND+ | DS1251WP-120 | DS1251Y-070IND+ |
| DS1251Y-100IND+ | DS1251Y-120IND+ | DS1251Y-70IND+ | DS1259S+TR | DS1259SN+TR |
| DS125BR111SQE/NOPB | DS125BR401ANJYT | DS125BR800ANJYT | DS125BR820NJYR | DS125DF410SQE/NOPB |
| DS125MB203SQE/NOPB | DS1267-010 | DS1267A1-010 | DS1267E-010/T | DS1267S-010 |
| DS1267S-010+TR | DS1267S-050 | DS1267S-100 | DS1287/1187 | DS12885Q |

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